Nonlinear Stationary Stuctures in Nonthermal Plasmas

L. A. Rios, R. M. O. Galvão

Centro Brasileiro de Pesquisas Físicas/CBPF Instituto Nacional de Ciência e Tecnologia de Sistemas Complexos/INCT-SC

Bernstein, Greene and Kruskal [1] showed the existence of an unlimited class of solutions to the Vlasov equation (BGK solutions) containing stationary potential structures. They proved that essentially arbitrary one-dimensional potential distributions can be derived, if a suitable number of particles trapped in potential troughs are added.

In the specific case of double layers (DL), which may be regarded as a BGK equilibrium with a potential drop ϕ_0 through the layer, some specific conditions must be fulfilled. One condition is the presence of free and trapped (or reflected) electrons and ions; a DL with only one type of trapped particle is exceptional, so usually all four classes of particles are required. Double layers are found in a wide variety of plasma environments, from discharge tubes to space plasmas, and are especially common in current-carrying plasmas.

In the present work we investigate the existence of stationary potential structures in nonthermal plasmas. Our model is based on nonthermal distribution functions, since the plasma distributions near a DL, for example, are usually strongly non-Maxwellian. Here the free and trapped electron populations are modeled by the family of κ distributions, which has been proven to be appropriate for modeling non-Maxwellian plasmas. Some preliminary results are shown and discussed.

Theory

Let us consider a Vlasov plasma of electrons and ions. As the intensity of the linear waves in such a plasma is increased, nonlinear effects become important. Here we discuss the BGK modes, named after Bernstein, Greene and Kruskal [1]. There are many practical applications of BGK modes, such as the nonlinear stage of a Landau damped Langmuir wave and the theory of DLs.

We already know that any distribution that is a function only of the constants of motion of the individual particles is a solution of the Vlasov equation. Here we are interested only in equilibrium

solutions that do not depend explicitly on time. A BGK mode involves an equilibrium distribution function in the presence of a spatially varying electrostatic potential, which is produced selfconsistently by the distribution function through Poisson's equation. Then for each particle species the Vlasov equation is (1D)

$$\left[v\frac{\partial}{\partial z} - \frac{q_j}{m_j}\frac{d\varphi}{dz}\frac{\partial}{\partial v}\right]f_j(z,v) = 0,$$
(1)

where $v \equiv v_z$ and j = e, i. The potential $\varphi(z)$ must be determined self-consistently through Poisson's equation

$$\frac{d^2\varphi}{dz^2} = 4\pi e \left[\int_{-\infty}^{\infty} f_e(z,v) dv - \int_{-\infty}^{\infty} f_i(z,v) dv \right].$$
(2)

If the ion and electron velocities are large enough, none of them are trapped in the electrostatic potential wells. We can also consider the case where some of the electrons and/or ions are trapped. It turns out that almost any potential $\varphi(z)$ can be constructed by choosing appropriate distributions of trapped/untrapped electrons and trapped/untrapped ions. Here we assume fixed ions and consider the case of trapped and untrapped electrons modeled by two different κ distributions. Working in the wave frame, the Vlasov equation (1) is solved by

• Free electrons - $E = u^2 - \phi \ge 0$

$$f_{\kappa f}(u) = A_{\kappa} \left\{ 1 + \frac{\left[\sigma\sqrt{(u^2 - \phi)} + u_D\right]^2}{(\kappa - 3/2)} \right\}^{-\kappa}$$
(3)

• Trapped electrons - $E=u^2-\phi<0$

$$f_{\kappa t}(u) = A_{\kappa} \left\{ 1 + \frac{\beta \left(u^2 - \phi\right) + u_D^2}{\left(\kappa - 3/2\right)} \right\}^{-\kappa}$$

$$\tag{4}$$

where $\sigma = sgn(u)$, $u = v/v_T$, $\phi = e\varphi/k_BT$ and $A_{\kappa} = \frac{N_0\Gamma(\kappa)}{[\pi(\kappa-3/2)]^{1/2}v_T\Gamma(\kappa-1/2)}$. u_D is the phase velocity of the structure (electron hole) in the laboratory frame and β is the trapping parameter, which is introduced to allow the description of different states of trapped particles: $\beta = 0$ represents an electron distribution which is flat in the trapped region, and $\beta < 0$ describes a situation in which there is a deficit of trapped particles [2].



Figure 1: Electron distribution function for $\beta=-3$ and $\kappa=2$ (electron hole in red)

Preliminary Results

First, we determine the normalized density $n_e(\phi)$ given by

$$n_{e}(\phi) = \frac{A_{\kappa} \left(\kappa - 3/2\right)^{\kappa}}{N_{0}} \left[I_{1}\left(\phi\right) + I_{2}\left(\phi\right) + I_{3}\left(\phi\right)\right],\tag{5}$$

where

$$I_1(\phi) = \int_{-\infty}^{-\sqrt{\phi}} \left\{ (\kappa - 3/2) + \left[-\sqrt{(u^2 - \phi)} + u_D \right]^2 \right\}^{-\kappa} du,$$
(6)

$$I_{2}(\phi) = \int_{-\sqrt{\phi}}^{\sqrt{\phi}} \left[(\kappa - 3/2) + \beta \left(u^{2} - \phi \right) + u_{D}^{2} \right]^{-\kappa} du,$$
(7)

$$I_{3}(\phi) = \int_{\sqrt{\phi}}^{\infty} \left\{ (\kappa - 3/2) + \left[\sqrt{(u^{2} - \phi)} + u_{D} \right]^{2} \right\}^{-\kappa} du.$$
(8)

In Figs. (2) and (3) we show the influence of the parameters κ and β in the normalized electron density.





Figure 2: $n_e(\phi)$ for $\beta = 0$ and $\kappa = 1.6$ (red), 2.5(green) and 4.8(yellow)

Figure 3: $n_e(\phi)$ for $\beta = -3$ and $\kappa = 1.6$ (red), 2.5 (green) and 4.8 (yellow)

Next Step

We now will proceed to determine the normalized electrostatic potential ϕ given by

$$\frac{d^2\phi}{d\zeta^2} = 2[n_e(\phi) - 1],\tag{9}$$

where $\zeta = \omega_{pe} z/v_t$. We intend to analyze the influence of various parameters on the behaviour of ϕ . We also will consider the case of trapped and untrapped ions and the possible electrostatic structures associated to them.

References

- 1. I. B. Bernstein, J. M. Greene, and M. D. Kruskal, Phys. Rev. 108, 546 (1957).
- 2. H. Schamel, *Physica Scripta* T2/1, 228 (1982).